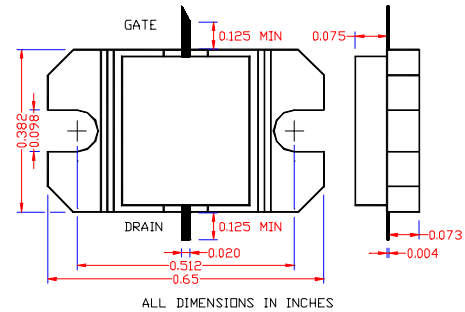


PRELIMINARY DATA SHEET
13.75-14.5GHz, 2W Internally Matched Power FET

- 13.75-14.5GHz BANDWIDTH AND INPUT/OUTPUT IMPEDANCE MATCHED TO 50 OHM
- EIA FEATURES HIGH PAE(30% TYPICAL)
- EIB FEATURES HIGH IP3(46dBm TYPICAL)
- +33.5/+33.0dBm TYPICAL P_{1dB} OUTPUT POWER FOR EIA/EIB
- 9.0/8.0dB TYPICAL G_{1dB} POWER GAIN FOR EIA/EIB
- NON-HERMETIC METAL FLANGE PACKAGE


ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

SYMBOLS	PARAMETERS/TEST CONDITIONS	EIA1314-2P			EIB1314-2P			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
P_{1dB}	Output Power at 1dB Compression $f=13.75\text{-}14.5\text{GHz}$ $V_{ds}=8\text{V}$, $I_{dsq}=0.5 I_{dss}$ (EIA), $0.6I_{dss}$ (EIB)	32.5	33.5		32	33.0		dBm
G_{1dB}	Gain at 1dB Compression $f=13.75\text{-}14.5\text{GHz}$ $V_{ds}=8\text{V}$, $I_{dsq}=0.5 I_{dss}$ (EIA), $0.6I_{dss}$ (EIB)	8	9		7	8		dB
PAE	Power Added Efficiency at 1dB compression $f=13.75\text{-}14.5\text{GHz}$ $V_{ds}=8\text{V}$, $I_{dsq}=0.5 I_{dss}$ (EIA), $0.6I_{dss}$ (EIB)		30			25		%
I_{d1dB}	Drain Current at 1dB Compression		880			850		mA
IP3	Output 3 rd Order Intercept Point $f=13.75\text{-}14.5\text{GHz}$ $V_{ds}=8\text{V}$, $I_{dsq}=0.5 I_{dss}$ (EIA), $0.6I_{dss}$ (EIB)		40			46*		dBm
I_{dss}	Saturated Drain Current $V_{ds}=3\text{V}$, $V_{gs}=0\text{V}$	1100	1440	1700	1100	1360	1700	mA
G_m	Transconductance $V_{ds}=3\text{V}$, $V_{gs}=0\text{V}$		1500			700		mS
V_p	Pinch-off Voltage $V_{ds}=3\text{V}$, $I_{ds}=12\text{mA}$		-1.0	-2.5		-2.0	-3.5	V
BV_{gd}	Drain Breakdown Voltage $I_{gd}=4.8\text{mA}$	-13	-15			-15		V
R_{th}	Thermal Resistance (Au-Sn Eutectic Attach)		8			8		$^\circ\text{C}/\text{W}$

*Typical -45dBc IM3 at $P_{out}=23\text{dBm}/\text{Tone}$

MAXIMUM RATINGS AT 25°C

SYMBOLS	PARAMETERS	ABSOLUTE ¹	CONTINUOUS ²
V_{ds}	Drain-Source Voltage	12V	8V
V_{gs}	Gate-Source Voltage	-8V	-3V
I_{ds}	Drain Current	I_{dss}	I_{dss}
I_{gsf}	Forward Gate Current	180mA	30mA
P_{in}	Input Power	32dBm	@ 3dB Compression
T_{ch}	Channel Temperature	175 $^\circ\text{C}$	150 $^\circ\text{C}$
T_{stg}	Storage Temperature	-65/175 $^\circ\text{C}$	-65/150 $^\circ\text{C}$
P_t	Total Power Dissipation	17W	14.2W

Note: 1. Exceeding any of the above ratings may result in permanent damage.

2. Exceeding any of the above ratings may reduce MTTF below design goals.